

**Vishay Semiconductors** 

# **Small Signal Fast Switching Diode**

### **FEATURES**

- Silicon epitaxial planar diode
- Low forward voltage drop
- · High forward current capability
- QuadroMELF package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- · High speed switch and general purpose
- · Use in computer and industrial applications

| PARTS  | TABLE                    |              |                       |               |  |
|--------|--------------------------|--------------|-----------------------|---------------|--|
| PART   | ORDERING CODE            | TYPE MARKING | CIRCUIT CONFIGURATION | REMARKS       |  |
| LS4150 | LS4150GS18 or LS4150GS08 | -            | Single                | Tape and reel |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                       |                    |       |      |  |  |
|--|-----------------------|--------------------|-------|------|--|--|
| PARAMETER  | TEST CONDITION        | SYMBOL             | VALUE | UNIT |  |  |
| Repetitive peak reverse voltage  |                       | V <sub>RRM</sub>   | 50    | V    |  |  |
| Reverse voltage  |                       | V <sub>R</sub>     | 50    | V    |  |  |
| Peak forward surge current   | t <sub>p</sub> = 1 μs | I <sub>FSM</sub>   | 4     | A    |  |  |
| Forward continuous current   |                       | I <sub>F</sub>     | 600   | mA   |  |  |
| Average forward current  | V <sub>R</sub> = 0    | I <sub>F(AV)</sub> | 300   | mA   |  |  |
| Power dissipation  |                       | P <sub>tot</sub>   | 500   | mW   |  |  |

| <b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                       |                   |             |      |  |  |
|---|---------------------------------------|-------------------|-------------|------|--|--|
| PARAMETER   | TEST CONDITION                        | SYMBOL            | VALUE       | UNIT |  |  |
| Thermal resistance junction to ambient air  | On PC board<br>50 mm x 50 mm x 1.6 mm | R <sub>thJA</sub> | 300         | K/W  |  |  |
| Junction temperature  |                                       | Tj                | 175         | °C   |  |  |
| Storage temperature range   |                                       | T <sub>stg</sub>  | -65 to +175 | °C   |  |  |

Rev. 2.2, 25-Jun-2024 1 Document Number: 85562



### LINKS TO ADDITIONAL RESOURCES



## **MECHANICAL DATA**

Case: QuadroMELF (SOD-80)

Weight: approx. 34 mg

Cathode band color: black

#### Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

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| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                 |       |      |       |      |
|---|--|-----------------|-------|------|-------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL          | MIN.  | TYP. | MAX.  | UNIT |
|   | I <sub>F</sub> = 1 mA  | V <sub>F</sub>  | 0.540 |      | 0.620 | V    |
|   | I <sub>F</sub> = 10 mA   | VF              | 0.660 |      | 0.740 | V    |
| Forward voltage   | I <sub>F</sub> = 50 mA   | V <sub>F</sub>  | 0.760 |      | 0.860 | V    |
|   | I <sub>F</sub> = 100 mA  | V <sub>F</sub>  | 0.820 |      | 0.920 | V    |
|   | I <sub>F</sub> = 200 mA  | VF              | 0.870 |      | 1     | V    |
| Reverse current   | V <sub>R</sub> = 50 V  | I <sub>R</sub>  |       |      | 100   | nA   |
| neverse current   | V <sub>R</sub> = 50 V, T <sub>j</sub> = 150 °C                                 | I <sub>R</sub>  |       |      | 100   | μA   |
| Diode capacitance   | $V_R = 0$ , f = 1 MHz, $V_{HF} = 50$ mV  | CD              |       |      | 2.5   | pF   |
| Reverse recovery time   | $I_F$ = $I_R$ = 10 mA to 100 mA,<br>$i_R$ = 0.1 x $I_R$ , $R_L$ = 100 $\Omega$ | t <sub>rr</sub> |       |      | 4     | ns   |

TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

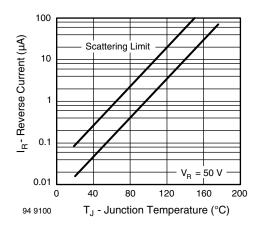


Fig. 1 - Reverse Current vs. Junction Temperature

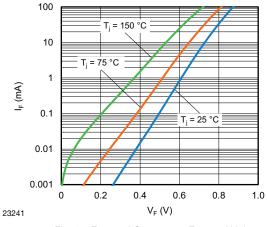
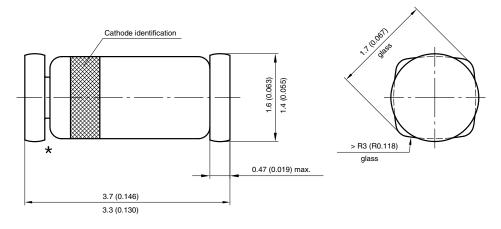


Fig. 2 - Forward Current vs. Forward Voltage

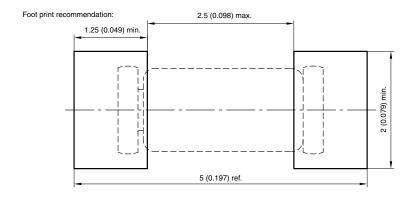


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#### PACKAGE DIMENSIONS in millimeters (inches): QuadroMELF (SOD-80)



<sup>★</sup> The gap between plug and glass can be either on cathode or anode side



Created - Date: 03.November.2003 Rev. 11 - Date: 07.June 2006 Document no.:6.560-5006.01-4 96 12071



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Revision: 01-Jan-2025

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